

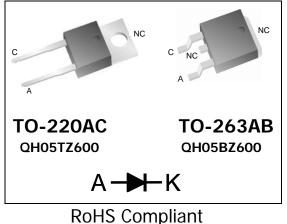
QH05TZ600, QH05BZ600 Qspeed[™] Family

600 V, 5 A H-Series PFC Diode

Product Summary

I _{F(AVG)}	5	А
V _{RRM}	600	V
Q _{RR} (Typ at 125 °C)	18.9	nC
I _{RRM} (Typ at 125 °C)	1.59	А
Softness t _B /t _A (Typ at 125 °C)	0.86	

Pin Assignment



Package uses Lead-free plating and Green mold compound. Halogen free per IEC 61249-2-21.

Absolute Maximum Ratings

General Description

This device has the lowest Q_{RR} of any 600 V silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- Power Factor Correction (PFC) boost diode
- Motor drive circuits
- DC-AC inverters

Features

- Low Q_{RR}, low I_{RRM}, low t_{RR}
- High dI_F/dt capable (1000 A / μs)
- Soft recovery

Benefits

- Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size & count
- Enables extremely fast switching

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

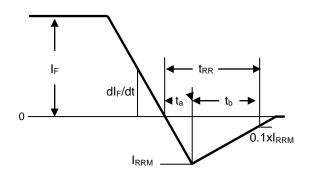
Symbol	Parameter	Conditions	Rating	Units
V _{RRM}	Peak repetitive reverse voltage	$T_{J} = 25 \ ^{\circ}C$	600	V
I _{F(AVG)}	Average forward current	$T_{J} = 150 \ ^{\circ}C, \ T_{C} = 109 \ ^{\circ}C$	5	Α
I _{FSM}	Non-repetitive peak surge current	60 Hz, $\frac{1}{2}$ cycle, T _C = 25 °C	50	Α
I _{FSM}	Non-repetitive peak surge current	V_2 cycle of t = 28 μ s Sinusoid, T _c = 25 °C	350	Α
TJ	Operating junction temperature range		-55 to 150	°C
T _{STG}	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6 mm from case, 10 sec	300	°C
VISOL	Isolation voltage (leads-to-tab)	AC, TO-220	2500	V
VISOL	Isolation voltage (leads-to-tab)	AC, TO-263	1500	V
P _D	Power dissipation	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	36.8	W

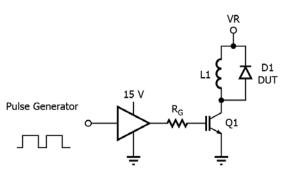
Thermal Resistance					
Symbol	Resistance from:	Conditions	Rating	Units	
$R_{ ext{ heta}JA}$	Junction to ambient	TO-220 (only)	62	°C/W	
$R_{ ext{ heta}JC}$	Junction to case		3.4	°C/W	

Electrical Specifications at T_J = 25 °C (unless otherwise specified)

Symbol	Parameter	Conditio	ns	Min	Тур	Мах	Units
	DC Characteristics						
	Doverse ourrent	V_R = 600 V, T_J = 25 $^\circ$	С	-	-	250	μΑ
I _R	Reverse current	$V_R = 600 V, T_J = 125$	°C	-	0.31	-	mA
M	Forward voltage	$I_F = 5 \text{ A}, T_J = 25 ^{\circ}\text{C}$		-	2.6	3.1	V
V _F	Forward voltage	$I_F = 5 \text{ A}, T_J = 150 ^{\circ}\text{C}$		-	2.2	-	V
CJ	Junction capacitance	$V_{R} = 10 V, 1 MHz$		-	17	-	рF
Dynamic	Dynamic Characteristics						
		$dI/dt = 200 A/\mu s$	$T_J = 25 \ ^{\circ}C$	-	10	-	ns
t _{RR}	Reverse recovery time	$V_R = 400 V$, $I_F = 5 A$	$T_J = 125 \ ^\circ C$	-	17.4	-	ns
	$dI/dt = 200 A/\mu s$	$T_J = 25 \ ^{\circ}C$	-	6.5	12	nC	
Q _{RR}	Q _{RR} Reverse recovery charge	$V_R = 400 V$, $I_F = 5 A$	$T_J = 125 \ ^\circ C$	-	18.9	-	nC
	Maximum reverse	dI/dt = 200 A/µs	$T_J = 25 \ ^\circ C$	-	1.0	1.55	А
I _{RRM}	$\label{eq:RRM} RRM \qquad recovery \ current \qquad V_R = \ 400 \ V, \ I_F = \ 5 \ A$	$T_J = 125 \ ^\circ C$	-	1.59	-	А	
	Softness factor = $\frac{t_B}{t_A}$	dI/dt = 200 A/µs	$T_J = 25 \ ^\circ C$	-	0.8	-	
S		$V_{R} = 400 V, I_{F} = 5 A$	$T_J = 125 \ ^\circ C$	-	0.86	-	

<u>Note to component engineers</u>: H-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)





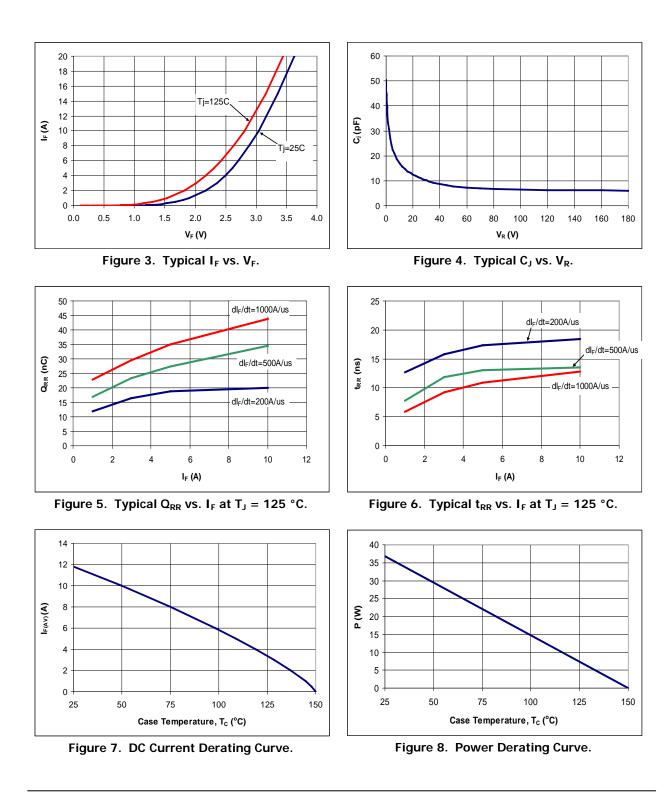
PI-7614-041315



Figure 2. Reverse Recovery Test Circuit.







Electrical Specifications at $T_J = 25$ °C (unless otherwise specified)

3 Rev 1.3 11/15

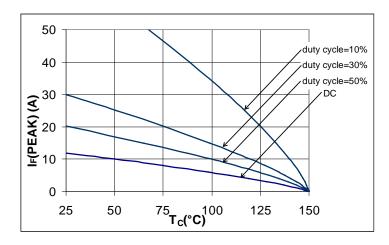


Figure 9. I_F (PEAK) vs. T_C , f = 70 kHz.

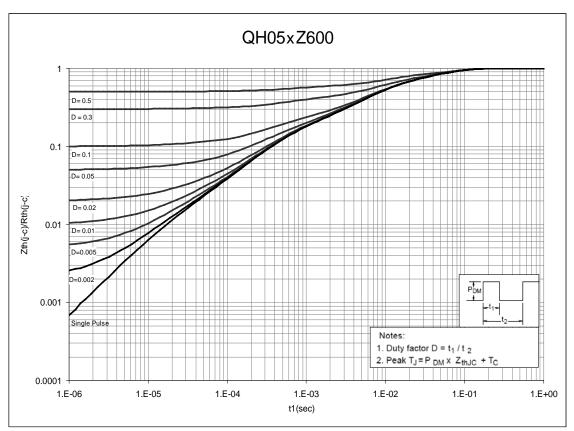


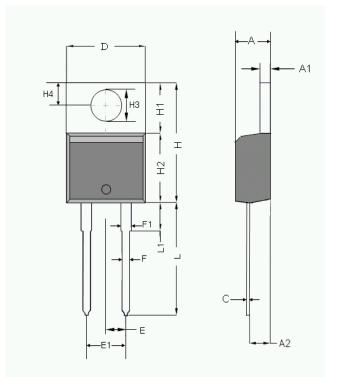
Figure 10. Normalized Maximum Transient Thermal Impedance.





Dimensional Outline Drawings

TO-220AC



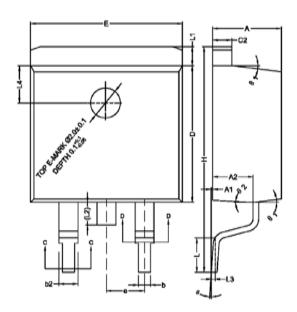
Millimeters Dim ΜΙΝ MAX 4.32 4.70 Α 1.40 A1 1.14 A2 2.03 2.79 С 0.34 0.610 D 9.65 10.67 Ε 2.49 2.59 E1 4.98 5.18 F 0.508 1.016 F1 1.14 1.78 н 14.71 16.51 5.84 6.795 H1 H2 8.40 9.00 H3 3.53 3.96 H4 2.54 3.05 L 12.70 14.22 L1 6.35 -





Dimensional Outline Drawings

TO-263AB

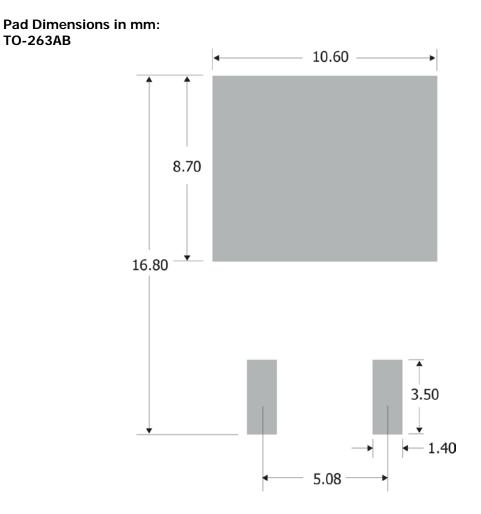


	Millimeters		
Dim	MIN	MAX	
А	4.40	4.70	
A1	0.00	0.25	
A2	2.59	2.79	
b	0.77	0.90	
b2	1.23	1.36	
c2	1.22	1.32	
D	9.05	9.25	
E	10.06	10.26	
е	2.54 BSC	2.54 BSC	
Н	14.70	15.50	
L	2.00	2.60	
L1	1.17	1.40	
L2	-	1.75	
L3	0.25 BSC	0.25 BSC	
L4	2.00 BSC	2.00 BSC	
Θ	0°	8°	
01	5°	9°	
02	1°	5°	

Mechanical Mounting Method	Maximum Torque / Pressure specification		
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)		
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm ²) or 175 lbf/in ²		







Footprint and Solder Pad Dimensions

Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
QH05TZ600	TO-220AC	50 units/tube
QH05BZ600	TO-263AB	800 units/reel

The information contained in this document is subject to change without notice.



QH05TZ600, QH05BZ600

Revision	Notes	Date
1.0	Released by Qspeed	01/10
1.1	Converted to Power Integrations Document	01/11
1.2	Added QH05BZ600	02/13
1.3	Updated with new Brand Style. Added footprint and solder pad dimension for TO-263AB package.	11/15





For the latest updates, visit our website: www.power.com

Power Integrations reserves the right to make changes to its products at any time to improve reliability or manufacturability. Power Integrations does not assume any liability arising from the use of any device or circuit described herein. POWER INTEGRATIONS MAKES NO WARRANTY HEREIN AND SPECIFICALLY DISCLAIMS ALL WARRANTIES INCLUDING, WITHOUT LIMITATION, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF THIRD PARTY RIGHTS.

Patent Information

The products and applications illustrated herein (including transformer construction and circuits' external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power

Integrations. A complete list of Power Integrations' patents may be found at www.power.com. Power Integrations grants its customers a license under certain patent rights as set forth at http://www.power.com/ip.htm.

Life Support Policy

POWER INTEGRATIONS PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF POWER INTEGRATIONS. As used herein:

- 1. A Life support device or system is one which, (i) is intended for surgical implant into the body, or (ii) supports or sustains life, and (iii) whose failure to perform, when properly used in accordance with instructions for use, can be reasonably expected to result in significant injury or death to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

The PI Logo, TOPSwitch, TinySwitch, LinkSwitch, LYTSwitch, InnoSwitch, DPA-Switch, PeakSwitch, CAPZero, SENZero, LinkZero, HiperTFS, HiperTCS, Ospeed, EcoSmart, Clampless, E-Shield, Filterfuse, FluxLink, StackFET, PI Expert and PI FACTS are trademarks of Power Integrations, Inc. Other trademarks are property of their respective companies. ©Copyright 2015 Power Integrations, Inc.

Power Integrations Worldwide Sales Support Locations

WORLD HEADQUARTERS

5245 Hellyer Avenue San Jose, CA 95138, USA. Main: +1-408-414-9200 Customer Service: Phone: +1-408-414-9665 Fax: +1-408-414-9765 e-mail: usasales@power.com

CHINA (SHANGHAI)

Rm 2410, Charity Plaza, No. 88, North Caoxi Road, Shanghai, PRC 200030 Phone: +86-21-6354-6323 Fax: +86-21-6354-6325

e-mail: chinasales@power.com

CHINA (SHENZHEN)

17/F, Hivac Building, No. 2, Keji Nan 8th Road, Nanshan District, Shenzhen, China, 518057 Phone: +86-755-8672-8689 Fax: +86-755-8672-8690 e-mail: chinasales@power.com

GERMANY

Lindwurmstrasse 114 80337, Munich Germany Phone: +49-895-527-39110 Fax: +49-895-527-39200 e-mail: eurosales@power.com

INDIA

#1, 14th Main Road Vasanthanagar Bangalore-560052 India Phone: +91-80-4113-8020 Fax: +91-80-4113-8023 e-mail: indiasales@power.com

ITALY

Via Milanese 20, 3rd. Fl. 20099 Sesto San Giovanni (MI) Italy Phone: +39-024-550-8701 Fax: +39-028-928-6009 e-mail: eurosales@power.com

JAPAN Kosei Dai-3 Building 2-12-11, Shin-Yokohama, Kohoku-ku Yokohama-shi, Kanagawa 222-0033 Japan Phone: +81-45-471-1021 Fax: +81-45-471-3717

KOREA

RM 602, 6FL Korea City Air Terminal B/D, 159-6 Samsung-Dong, Kangnam-Gu, Seoul, 135-728 Korea Phone: +82-2-2016-6610 Fax: +82-2-2016-6630 e-mail: koreasales@power.com

e-mail: japansales@power.com

SINGAPORE

51 Newton Road, #19-01/05 Goldhill Plaza Singapore, 308900 Phone: +65-6358-2160 Fax: +65-6358-2015 e-mail: singaporesales@power.com

TAIWAN

5F, No. 318, Nei Hu Rd., Sec. 1 Nei Hu District Taipei 11493, Taiwan R.O.C. Phone: +886-2-2659-4570 Fax: +886-2-2659-4550 e-mail: taiwansales@power.com

UK

Cambridge Semiconductor, a Power Integrations company Westbrook Centre, Block 5, 2nd Floor Milton Road Cambridge CB4 1YG Phone: +44 (0) 1223-446483 e-mail: eurosales@power.com





Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Power Integrations: QH05TZ600 QH05BZ600